

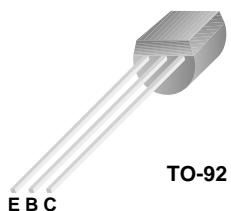
# PN2222A / MMBT2222A / PZT2222A

## NPN General Purpose Amplifier

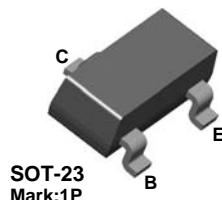
### Features

- This device is for use as a medium power amplifier and switch requiring collector currents up to 500mA.
- Sourced from process 19.

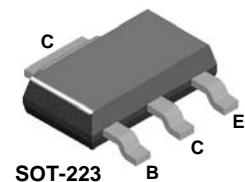
**PN2222A**



**MMBT2222A**



**PZT2222A**



### Absolute Maximum Ratings \* $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CEO}$	Collector-Emitter Voltage	40	V
$V_{CBO}$	Collector-Base Voltage	75	V
$V_{EBO}$	Emitter-Base Voltage	6.0	V
$I_C$	Collector Current	1.0	A
$T_{STG}$	Operating and Storage Junction Temperature Range	- 55 ~ 150	°C

\* This ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

### NOTES:

- 1) These rating are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

### Thermal Characteristics $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Max.			Units
		PN2222A	*MMBT2222A	**PZT2222A	
$P_D$	Total Device Dissipation Derate above 25°C	625 5.0	350 2.8	1,000 8.0	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3			°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	125	°C/W

\* Device mounted on FR-4 PCB 1.6" x 1.6" x 0.06".

\*\* Device mounted on FR-4 PCB 36mm x 18mm x 1.5mm; mounting pad for the collector lead min. 6cm<sup>2</sup>.

**Electrical Characteristics**  $T_a = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
<b>Off Characteristics</b>					
$\text{BV}_{(\text{BR})\text{CEO}}$	Collector-Emitter Breakdown Voltage *	$I_C = 10\text{mA}, I_B = 0$	40		V
$\text{BV}_{(\text{BR})\text{CBO}}$	Collector-Base Breakdown Voltage	$I_C = 10\mu\text{A}, I_E = 0$	75		V
$\text{BV}_{(\text{BR})\text{EBO}}$	Emitter-Base Breakdown Voltage	$I_E = 10\mu\text{A}, I_C = 0$	6.0		V
$I_{\text{CEX}}$	Collector Cutoff Current	$V_{\text{CE}} = 60\text{V}, V_{\text{EB}(\text{off})} = 3.0\text{V}$		10	nA
$I_{\text{CBO}}$	Collector Cutoff Current	$V_{\text{CB}} = 60\text{V}, I_E = 0$ $V_{\text{CB}} = 60\text{V}, I_E = 0, T_a = 125^\circ\text{C}$		0.01 10	$\mu\text{A}$ $\mu\text{A}$
$I_{\text{EBO}}$	Emitter Cutoff Current	$V_{\text{EB}} = 3.0\text{V}, I_C = 0$		10	nA
$I_{\text{BL}}$	Base Cutoff Current	$V_{\text{CE}} = 60\text{V}, V_{\text{EB}(\text{off})} = 3.0\text{V}$		20	nA
<b>On Characteristics</b>					
$h_{\text{FE}}$	DC Current Gain	$I_C = 0.1\text{mA}, V_{\text{CE}} = 10\text{V}$ $I_C = 1.0\text{mA}, V_{\text{CE}} = 10\text{V}$ $I_C = 10\text{mA}, V_{\text{CE}} = 10\text{V}$ $I_C = 10\text{mA}, V_{\text{CE}} = 10\text{V}, T_a = -55^\circ\text{C}$ $I_C = 150\text{mA}, V_{\text{CE}} = 10\text{V}^*$ $I_C = 150\text{mA}, V_{\text{CE}} = 1\text{V}^*$ $I_C = 500\text{mA}, V_{\text{CE}} = 10\text{V}^*$	35 50 75 35 100 50 40	300	
$V_{\text{CE}(\text{sat})}$	Collector-Emitter Saturation Voltage *	$I_C = 150\text{mA}, I_B = 15\text{mA}$ $I_C = 500\text{mA}, I_B = 50\text{mA}$		0.3 1.0	V V
$V_{\text{BE}(\text{sat})}$	Base-Emitter Saturation Voltage *	$I_C = 150\text{mA}, I_B = 15\text{mA}$ $I_C = 500\text{mA}, I_B = 50\text{mA}$	0.6	1.2 2.0	V V
<b>Small Signal Characteristics</b>					
$f_T$	Current Gain Bandwidth Product	$I_C = 20\text{mA}, V_{\text{CE}} = 20\text{V}, f = 100\text{MHz}$	300		MHz
$C_{\text{obo}}$	Output Capacitance	$V_{\text{CB}} = 10\text{V}, I_E = 0, f = 1\text{MHz}$		8.0	pF
$C_{\text{ibo}}$	Input Capacitance	$V_{\text{EB}} = 0.5\text{V}, I_C = 0, f = 1\text{MHz}$		25	pF
$r_b' C_c$	Collector Base Time Constant	$I_C = 20\text{mA}, V_{\text{CB}} = 20\text{V}, f = 31.8\text{MHz}$		150	pS
NF	Noise Figure	$I_C = 100\mu\text{A}, V_{\text{CE}} = 10\text{V}, R_S = 1.0\text{K}\Omega, f = 1.0\text{KHz}$		4.0	dB
$\text{Re}(h_{ie})$	Real Part of Common-Emitter High Frequency Input Impedance	$I_C = 20\text{mA}, V_{\text{CE}} = 20\text{V}, f = 300\text{MHz}$		60	$\Omega$
<b>Switching Characteristics</b>					
$t_d$	Delay Time	$V_{\text{CC}} = 30\text{V}, V_{\text{EB}(\text{off})} = 0.5\text{V}, I_C = 150\text{mA}, I_{B1} = 15\text{mA}$		10	ns
$t_r$	Rise Time			25	ns
$t_s$	Storage Time	$V_{\text{CC}} = 30\text{V}, I_C = 150\text{mA}, I_{B1} = I_{B2} = 15\text{mA}$		225	ns
$t_f$	Fall Time			60	ns

\* Pulse Test: Pulse Width  $\leq 300\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$

## Typical Performance Characteristics

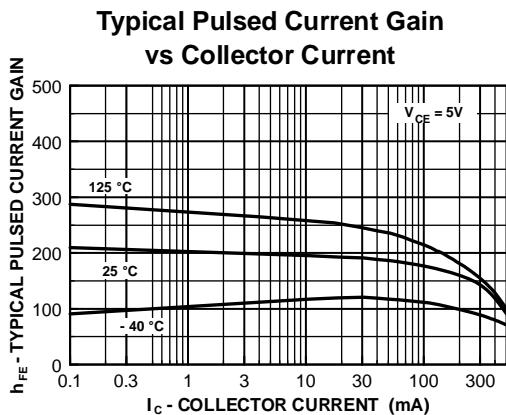


Figure 1. Typical Pulsed Current Gain vs Collector Current

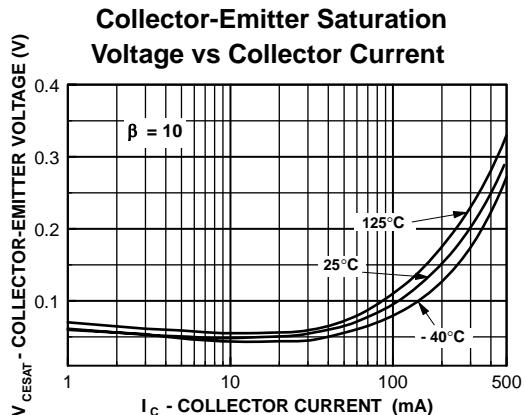


Figure 2. Collector-Emitter Saturation Voltage vs Collector Current

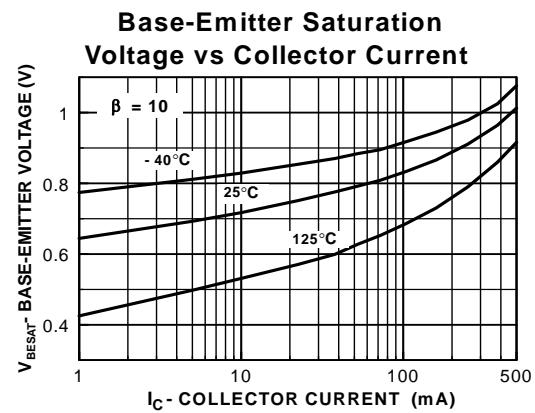


Figure 3. Base-Emitter Saturation Voltage vs Collector Current

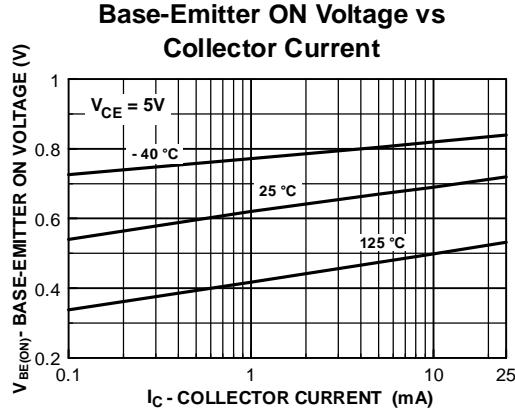


Figure 4. Base-Emitter On Voltage vs Collector Current

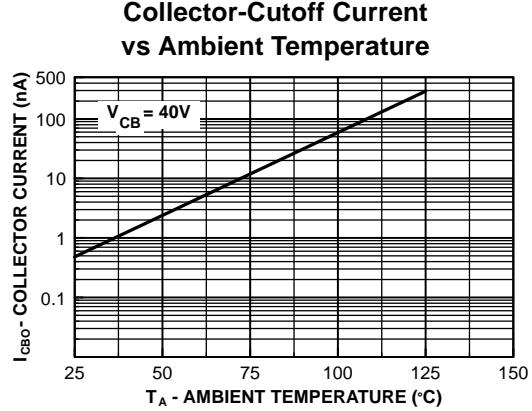


Figure 5. Collector Cutoff Current vs Ambient Temperature

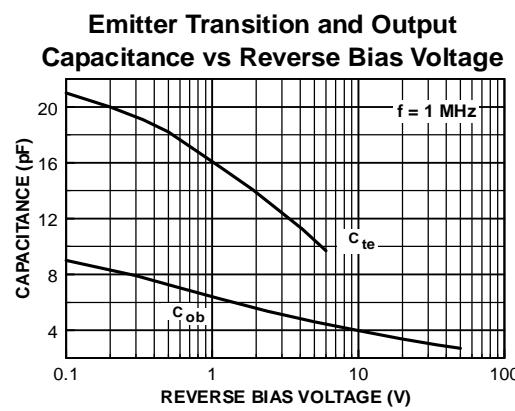


Figure 6. Emitter Transition and Output Capacitance vs Reverse Bias Voltage

## Typical Performance Characteristics

(Continued)

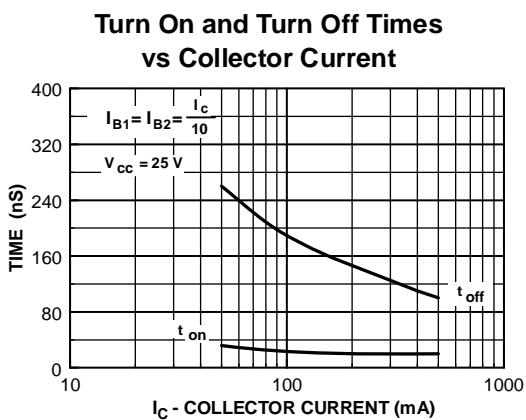


Figure 7. Turn On and Turn Off Times vs Collector Current

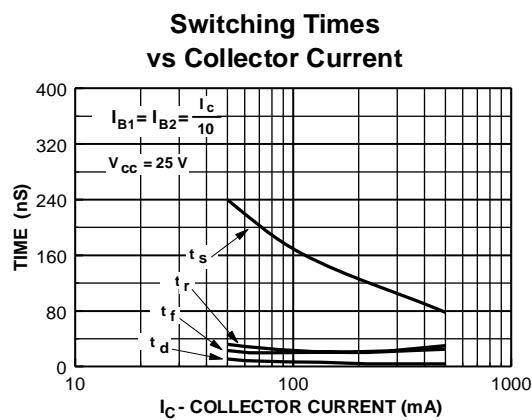


Figure 8. Switching Times vs Collector Current

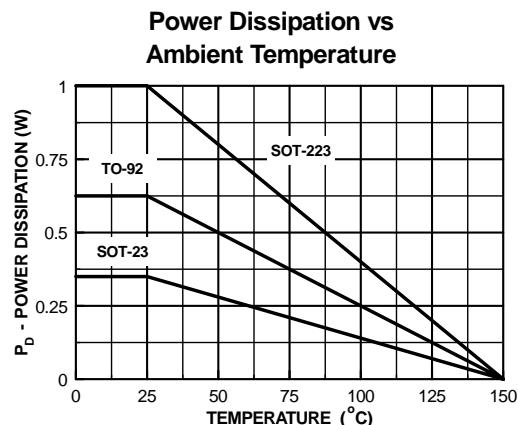


Figure 9. Power Dissipation vs Ambient Temperature

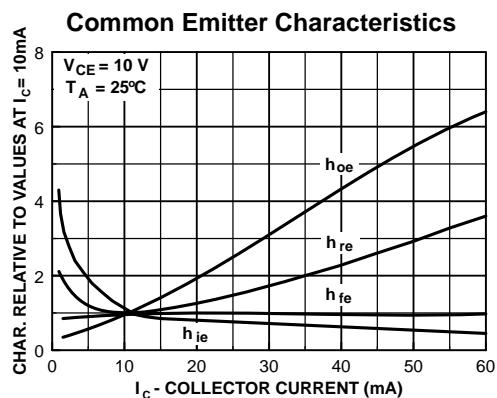


Figure 10. Common Emitter Characteristics

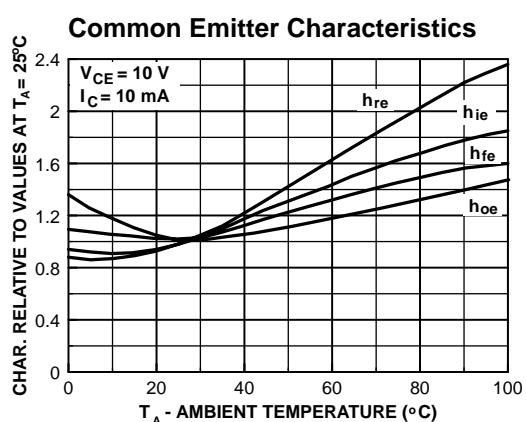


Figure 11. Common Emitter Characteristics

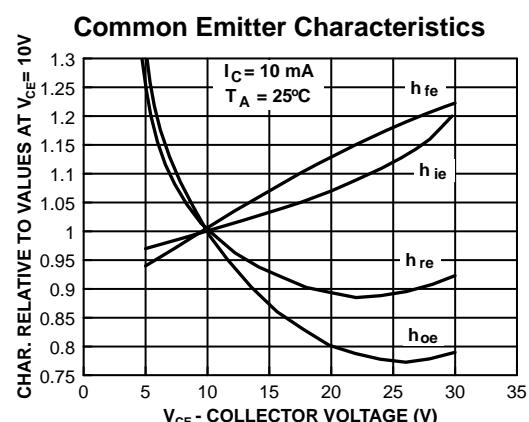


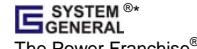
Figure 12. Common Emitter Characteristics



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